NSN 5962-01-303-7723



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Memory Microcircuit - Page 1 of 2 **Body Length:** 1.280 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** 0.185 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and monolithic and programmed **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 14 input **Case Outline Source And Designator:** D-9 mil-m-38510 **Current Rating Per Characteristic:** 185.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Capitance Rating Per Characteristic:** 4.00 input picofarads and 8.00 output picofarads **Time Rating Per Chacteristic:** 90.00 nanoseconds delay Memory Device Type: Prom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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